PCN Nu	mber:	202	31011	004.2						F	PCN D	ate:	October 13, 2023
Title:	Qualific	ation	of Cu	as an a	ılterr	ate bo	ond w	ire for sele	ect de	evic	es		
Custom	ner Conta	ct:	Chan	ge Man	ager	nent T	eam	Dept:	Qua	ality	y Serv	ices	
Propos	ed 1 st Shi	p Da	te:	Apr 12	2, 20	24					uests until:	Nov	12, 2023*
*Sample	requests	rece	ived a	fter No	v 12	, 2023	will n	ot be sup	porte	d.			
	embly Sit	e				Desig	n				Wafe	r Bum	p Material
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	chanical S	•			<u> </u>	Test			Į	4			Material -
	king/Ship	ping/l	Labelin	g	<u> Ш</u>	Test			l		Wafe	r Fab	Process
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	will remai			•		acility		ed in "Prod piece part			as fo		
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Continui 1) To a elec 2) Maxi	ty of supp lign with trical prop	ply. world perties bility	s within	our Ass	semb			iring with		nce	d mec	hanica	al and
Anticipa	ated imp	act o	n Forr	n, Fit,	Fune	ction,	Quali	ty or Reli	abilit	у (positi	ve / r	negative):
None								-			-		
Impact	on Envir	onme	ental F	Ratings	5								
	Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.												
<u> </u>	RoHS				ACH			Green		S			C 62474
☐ No	Change			No Cha	nge			No Chan	ge			No C	hange
Change	s to proc	luct i	dentif	icatior	res	ulting	from	this PCN	:				
None	None												
Product	t Affected	d:											
AMC33	AMC3301QDWERQ1 AMC3302QDWERQ1 AMC3330QDWERQ1 AMC3336QDWERQ1												

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) Approve Date 07-September -2023

Product Attributes

Attributes	Qual Device:	QBS Process Reference:	QBS Process Reference:	QBS Product Reference:
Attributes	AMC3311QDWERQ1	<u>ISO7741FQDWQ1</u>	AMC1305M25QDWRQ1	AMC131M03QDFMRQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Signal Chain	Interface	Signal Chain	Signal Chain
Wafer Fab Supplier	MH8, AIZU, AIZU, MH8	MH8, MH8	DP1DM5, DP1DM5, AIZU	DMOS6, MH8, MH8
Assembly Site	TAI	TAI	TAI	TAI
Package Group	SOIC	SOIC	SOIC	SOIC
Package Designator	DWE	DW	DW	DFM
Pin Count	16	16	16	20

QBS: Qual By Similarity

Qual Device AMC3311QDWERQ1 is qualified at MSL3 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

HAST A2 JEDEC JESD22- A110 A110	Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AMC3311QDWERQ1	QBS Process Reference: ISO7741FQDWQ1	QBS Process Reference: AMC1305M25QDWRQ1	QBS Product Reference: AMC131M03QDFMRQ1
PC	est Group A	A - Acce	lerated Environ	ment St	ress Tes	its						
HAST A2 JESD22- A100 3 77 Biased HAST 110C/85%RH Hours 1/77/0 - - - - -	PC	A1	STD-020 JESD22-	3	77	Preconditioning	MSL3 260C		No Fails	-	-	No Fails
AC/UHAST A3	HAST	A2	JESD22-	3	77	Biased HAST	110C/85%RH		1/77/0	-		3/231/0
TC A4 JESD22- A104 and JESD22- A104 and MIL-STD883 Method 2011 3 77 Temperature Cycle -65C/150C 500 Cycles 3/231/0 -	AC/UHAST	АЗ	JESD22- A102/JEDEC JESD22-	3	77	Unbiased HAST	110C/85%RH		3/231/0			3/231/0
HTSL A6 JEDEC 1 45 High Temperature Storage Life 175C 500 Hours 1/45/0 - - - -	rc .	A4	JESD22- A104 and	3	77		-65C/150C		3/231/0	-	-	3/231/0
HTSL A6	C-BP	A4		1	5			-	1/5/0	-	-	-
HTOL B1 JEDEC 1 77 Life Test 125C 1000 - 3/231/0 - HTOL B1 JEDEC JESD22- A108 1 77 Life Test 150C 408 Hours - 3/231/0 - 3/231/0	ITSL	A6	JESD22-	1	45	Temperature	175C		1/45/0	-	-	3/135/0
HTOL B1 JESD22- A108 1 77 Life Test 125C 1000 Hours - 3/231/0 - HTOL B1 JEDEC JESD22- A108 1 77 Life Test 150C 408 Hours - - 3/231/0	est Group E	B - Acce	lerated Lifetime	e Simula	tion Test	ts						
HTOL B1 JESD22- A108 1 77 Life Test 150C 408 Hours 3/231/0	HTOL	B1	JESD22-	1	77	Life Test	125C		-	3/231/0		
150 0100	HTOL	B1	JESD22-	1	77	Life Test	150C		-	-	3/231/0	-
ELFR B2 AEC Q100- 008 1 77 Early Life Failure Rate 125C 48 Hours - 3/2400/0 -	ELFR	B2	AEC Q100- 008	1	77	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-	-
ELFR B2 AEC Q100- 008 1 77 Early Life Failure Rate 150C 24 Hours 3/2400/0	ELFR	B2		1	77		150C		-	-	3/2400/0	

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AMC3311QDWERQ1	QBS Process Reference: ISO7741FQDWQ1	QBS Process Reference: AMC1305M25QDWRQ1	QBS Product Reference: AMC131M03QDFMRQ1
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	-	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	-	-	-
SD	СЗ	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage	-	-	-	-	1/15/0
SD	СЗ	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	1	10	Physical Dimensions	Cpk>1.67	-	3/30/0	-	-	
Test Group	D - Die F	abrication Relia	ability Te	sts							
EM	D1	JESD61	-		Electromigration		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35		-	Time Dependent Dielectric Breakdown			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28			Hot Carrier Injection		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-		Stress Migration		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verification	n Tests								
ESD	E2	AEC Q100- 002	1	3	ESD HBM		2000 Volts	1/3/0	-	-	-
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	500 Volts	1/3/0	-		
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	1/6/0	-	-	-
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0	-	-	-

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB/HAST, TC/PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines) Approve Date 26-September -2023

Product Attributes

Attributes	Qual Device:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:
Attributes	AMC3330QDWERQ1	INA215AQDCKRQ1	IS07741FQDWQ1	AMC3301QDWERQ1	ISOW7841FQDWEQ1	TPSi3050QDWZRQ1	UCC12051QDVERQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Signal Chain	Signal Chain	Interface	Signal Chain	Interface	Power Management	Power Management
Wafer Fab Supplier	AIZU, AIZU, MH8, MH8	AIZU	MH8, MH8	AIZU, AIZU, MH8, MH8	DP1DM5, DP1DM5	RFAB, RFAB	RFAB, RFAB
Assembly Site	TAI	TFME	TAI	TAI	TAI	TAI	TAI
Package Group	SOIC	SOT	SOIC	SOIC	SOIC	SOIC	SOIC
Package Designator	DWE	DCK	DW	DWE	DWE	DWZ	DVE
Pin Count	16	6	16	16	16	8	16

QBS: Qual By Similarity

Qual Device AMC3330QDWERQ1 is qualified at MSL3 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name	Condition	Duration	Qual Device: AMC3330QDWERQ1	QBS Process Reference:	QBS Process Reference:	QBS Product Reference:	QBS Package Reference:	QBS Package Reference:	QBS Package Reference:
Test Group /	A - Accel	erated Environ		ress Tes	its				INA215AQDCKRQ1	ISO7741FQDWQ1	AMC3301QDWERQ1	ISOW7841FQDWEQ1	TPSi3050QQWZRQ1	UCC12051QDVERQ1
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL3 260C		3/0/0	-	-	3/0/0	-	3/0/0	3/0/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	110C/85%RH	264 Hours	-			-	-	3/231/0	3/231/0
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	-		-	3/231/0	-		-
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	110C/85%RH	264 Hours	1/20/0	-		1/77/0	-	3/231/0	-
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Unbiased HAST	130C/85%RH	96 Hours	-	-		3/231/11	-	-	
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-55C/150C	1000 Cycles		-			-	3/231/0	
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	1/20/0	-	-	3/231/0	-		3/231/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-					3/15/0	-	1/5/0	3/15/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	170C	620 Hours				3/231/0			
Test Group I	B - Acce	lerated Lifetime	e Simula	tion Tes	ts									
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours	-	3/231/0	3/231/0		-	-	-
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	150C	408 Hours	-	-	-	3/231/3 ²	-		-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	3/2400/0		-		
Test Group	C - Pack	age Assembly	Integrity	Tests										
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	3/90/0	3/90/0	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	1/30/0	-	-	3/90/0	3/90/0	-	-
SD	СЗ	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage	-		-		1/15/0	1/15/0	-	
SD	СЗ	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	-	1/15/0	1/15/0	-	
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67		1/10/0	-	-	-	2/20/0	-	
Test Group I	D - Die F	abrication Relia	ıbility Te	sts										
EM	D1	JESD61			Electromigration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements

Туре	#	Test Spec	Min	SS/	Test Name	Condition	Duration	Qual Device:	QBS Process Reference:	QBS Process Reference:	QBS Product Reference:	QBS Package Reference:	QBS Package Reference:	QBS Package Reference:
-,,,-	-		Qty	Lot				AMC3330QDWERQ1	INA215AQDCKRQ1	ISO7741FQDWQ1	AMC3301QDWERQ1	ISOW7841FQDWEQ1	TPSi3050QDWZRQ1	UCC12051QDVERQ1
TDDB	D2	JESD35	-		Time Dependent Dielectric Breakdown		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
нсі	D3	JESD60 & 28			Hot Carrier Injection		-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4				Negative Bias Temperature Instability			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5				Stress Migration			Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verificatio	n Tests											
ESD	E2	AEC Q100- 002	1	3	ESD HBM		3500 Volts	-	-	-	3/9/0			
ESD	E3	AEC Q100- 011	1	3	ESD CDM		1500 Volts	-	-	-	3/9/0			
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	-	-		3/18/0			
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-		-	3/90/0			-

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles **Ambient Operating Temperature by Automotive Grade Level:**

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB/HAST, TC/PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Qualification Report

Automotive New Product Qualification Summary (As per AEC-Q100, AEC-Q006, and JEDEC Guidelines)
Approve Date 07-September -2023

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AMC3311QDWERQ1	QBS Reference: AMC131M03QDFMRQ1
Test G	roup A - A	Accelerated Environmer	nt Stress	Tests					
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Preconditioning	MSL3 260C	-	3/0/0	3/0/0
PC	A1.1	-	3	22	SAM Precon Pre	Review for delamination	-	3/66/0	3/66/0
PC	A1.2	-	3	22	SAM Precon Post	Review for delamination	-	3/66/0	3/66/0
HAST	A2.1	JEDEC JESD22-A110	3	77	Biased HAST	110C/85%RH	264 Hours	1/77/0	3/231/0
HAST	A2.1.2	-	3	1	Cross Section, post bHAST, 1X	Post stress cross section	Completed	1/1/0	3/3/0
HAST	A2.1.3	-	3	30	Wire Bond Shear, post bHAST, 1X	Post stress	Wires	1/30/0	3/90/0

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: AMC3311QDWERQ1	QBS Reference: AMC131M03QDFMRQ1
HAST	A2.1.4	-	3	30	Bond Pull over Stitch, post bHAST, 1X	Post stress	Wires	1/30/0	3/90/0
HAST	A2.1.5	-	3	30	Bond Pull over Ball, post bHAST, 1X	Post stress	Wires	1/30/0	3/90/0
HAST	A2.2	JEDEC JESD22-A110	3	70	Biased HAST	110C/85%RH	528 Hours	1/70/0	3/210/0
HAST	A2.2.1	-	3	22	SAM Analysis, post bHAST 2X	Review for delamination	Completed	1/22/0	3/66/0
HAST	A2.2.2	-	3	1	Cross Section, post bHAST, 2X	Post stress cross section	Completed	1/1/0	3/3/0
HAST	A2.2.3	-	3	30	Wire Bond Shear, post bHAST, 2X	Post stress	Wires	1/30/0	3/90/0
HAST	A2.2.4	-	3	30	Bond Pull over Stitch, post bHAST, 2X	Post stress	Wires	1/30/0	3/90/0
HAST	A2.2.5	-	3	30	Bond Pull over Ball, post bHAST, 2X	Post stress	Wires	1/30/0	3/90/0
тс	A4.1	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	3/231/0
тс	A4.1.1	-	3	22	SAM Analysis, post TC 1X	Review for delamination	Completed	3/66/0	3/66/0
тс	A4.1.2	-	3	1	Cross Section, post TC, 1X	Post stress cross section	Completed	3/3/0	3/3/0
тс	A4.1.3	-	3	30	Wire Bond Shear, post TC, 1X	Post stress	Wires	3/90/0	3/90/0
тс	A4.1.4	-	3	30	Bond Pull over Stitch, post TC, 1X	Post stress	Wires	3/90/0	3/90/0
тс	A4.1.5	-	3	30	Bond Pull over Ball, post TC, 1X	Post stress	Wires	3/90/0	3/90/0
тс	A4.2	JEDEC JESD22-A104 and Appendix 3	3	70	Temperature Cycle	-65C/150C	1000 Cycles	3/210/0	3/210/0
тс	A4.2.1	-	3	22	SAM Analysis, post TC, 2X	Review for delamination	Completed	3/66/0	3/66/0
тс	A4.2.2	-	3	1	Cross Section, post TC, 2X	Post stress cross section	Completed	3/3/0	3/3/0
тс	A4.2.3	-	3	30	Wire Bond Shear, post TC, 2X	Post stress	Wires	3/90/0	3/90/0
тс	A4.2.4	-	3	30	Bond Pull over Stitch, post TC, 2X	Post stress	Wires	3/90/0	3/90/0
тс	A4.2.5	-	3	30	Bond Pull over Ball, post TC, 2X	Post stress	Wires	3/90/0	3/90/0
HTSL	A6.1	JEDEC JESD22-A103	3	45	High Temperature Storage Life	175C	500 Hours	1/45/0	3/135/0
HTSL	A6.1.1	-	3	1	Cross Section, post HTSL, 1X	Post stress cross section	Completed	1/1/0	3/3/0
HTSL	A6.2	JEDEC JESD22-A103	3	44	High Temperature Storage Life	175C	1000 Hours	1/44/0	3/132/0
HTSL	A6.2.1	-	3	1	Cross Section, post HTSL, 2X	Post stress cross section	Completed	1/1/0	3/3/0
Test G	roup C - F	Package Assembly Integ	rity Test	s					
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	4/120/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	4/120/0

QBS: Qual By Similarity

Qual Device AMC3311QDWERQ1 is qualified at MSL3 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40C to +150C Grade 1 (or Q): -40C to +125C Grade 2 (or T): -40C to +105C Grade 3 (or I): -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

ZVEI ID reference: SEM-PA-08

For questions regarding this notice, e-mails can be sent to Change Management team or your local Field Sales Representative.

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